Power Products Division

Advance Information

SINGLE CHANNEL DRIVER

The MPIC2117 is a high voltage, high speed, power MOSFET and IGBT driver. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS outputs. The output drivers feature a high pulse current buffer stage designed for minimum driver cross—conduction. The floating channel can be used to drive an N—channel power MOSFET or IGBT in the high side or low side configuration which operates from 10 to 600 volts.

- Floating Channel Designed for Bootstrap Operation
- Fully Operational to +600 V
- Tolerant to Negative Transient Voltage
- dV/dt Immune
- Gate Drive Supply Range from 10 to 20 V
- Undervoltage Lockout
- CMOS Schmitt-triggered Input with Pull-down
- Output In Phase with Input

PRODUCT SUMMARY

 VOFFSET
 600 V MAX

 IO+/ 200 mA/420 mA

 VOUT
 10 - 20 V

 ton/off (typical)
 125 & 105 ns

MPIC2117

SINGLE CHANNEL DRIVER



P SUFFIX PLASTIC PACKAGE CASE 626–05



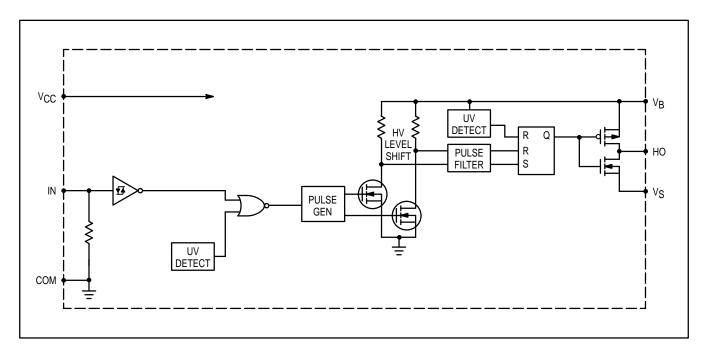
D SUFFIXPLASTIC PACKAGE
CASE 751–05
(SO–8)

ORDERING INFORMATION

Device	Package
MPIC2117D	SOIC
MPIC2117P	PDIP



SIMPLIFIED BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The Thermal Resistance and Power Dissipation ratings are measured under board mounted and still air conditions.

Rating		Symbol	Min	Max	Unit
High Side Floating Supply Absolute Voltage High Side Floating Supply Offset Voltage High Side Floating Output Voltage Logic Supply Voltage Logic Input Voltage		VB VS VHO VCC VIN	-0.3 V _B -25 V _S -0.3 -0.3 -0.3	625 V _B +0.3 V _B +0.3 25 V _{CC} +0.3	VDC
Allowable Offset Supply Voltage Transient		dV _S /dt	-	50	V/ns
*Package Power Dissipation @ T _A ≤ +25°C	(8 Lead DIP) (8 Lead SOIC)	P _D	- -	1.0 0.625	Watt
Thermal Resistance, Junction to Ambient	(8 Lead DIP) (8 Lead SOIC)	$R_{ heta JA}$	- -	125 200	°C/W
Operating and Storage Temperature		T _j , T _{stg}	-55	150	°C
Lead Temperature for Soldering Purposes, 10 se	conds	TL	-	260	°C

RECOMMENDED OPERATING CONDITIONS

The Input/Output logic timing Diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions. The V_S offset rating is tested with all supplies biased at 15 V differential.

High Side Floating Supply Absolute Voltage	V _B	V _S +10	V _S +20	V
High Side Floating Supply Offset Voltage	VS	Note 1	600	
High Side Floating Output Voltage	VHO	٧s	VB	
Logic Supply Voltage	Vcc	10	20	
Logic Input Voltage	VIN	0	VCC	
Ambient Temperature	T _A	-40	125	°C

Note 1: Logic operational for V_S of –5 to +600 V. Logic state held for V_S of –5 V to –V_{BS}.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

Characteristic	Symbol	Min	Тур	Max	Unit	
OTATIO EL FOTDIO AL QUADA OTEDIOTIOS						

STATIC ELECTRICAL CHARACTERISTICS

 V_{BIAS} (V_{CC} , V_{BS}) = 15 V unless otherwise specified. The V_{IN} , V_{TH} and I_{IN} parameters are referenced to COM. The VO and IO parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

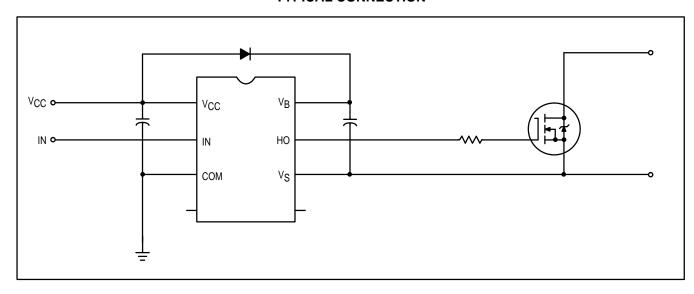
Logic "1" Input Voltage @ V _{CC} = 10 V	VIH	6.4	_	_	V _{DC}
Logic "1" Input Voltage @ V _{CC} = 15 V	VIH	9.5	-	_	1
Logic "1" Input Voltage @ V _{CC} = 20 V	ViH	12.6	-	-	
Logic "0" Input Voltage @ V _{CC} = 10 V	VIL	-	-	3.8	
Logic "0" Input Voltage @ V _{CC} = 15 V	VIL	-	-	6.0	
Logic "0" Input Voltage @ V _{CC} = 20 V	VIL	-	-	8.3	
High Level Output Voltage, V _{BS} -V _O @ V _{IN} = V _{IH} , I _O = 0 A	VOH	-	-	100	mV
Low Level Output Voltage, V _O @ V _{IN} = V _{IL} , I _O = 0 A	V _{OL}	_	-	100	
Offset Supply Leakage Current @ V _B = V _S = 600 V	ILK	-	-	50	μΑ
Quiescent V _{BS} Supply Current @ V _{IN} = 0 V or V _{CC}	IQBS	_	50	_	
Quiescent V _{CC} Supply Current @ V _{IN} = 0 V or V _{CC}	IQCC	-	70	-	
Logic "1" Input Bias Current @ V _{IN} = 15 V	I _{IN+}	-	20	40	
Logic "0" Input Bias Current @ V _{IN} = 0 V	I _{IN} _	ı	-	1.0	
V _{BS} Supply Undervoltage Positive Going Threshold	V _{BSUV+}	ı	8.5	_	V
VBS Supply Undervoltage Negative Going Threshold	V _{BSUV} -	ı	8.2	_	
V _{CC} Supply Undervoltage Positive Going Threshold	VCCUV+	ı	8.6	_	
V _{CC} Supply Undervoltage Negative Going Threshold	VCCUV-	_	8.2	_	
Output High Short Circuit Pulsed Current @ $V_{OUT} = 0 \text{ V}$, $V_{IN} = 15 \text{ V}$, $PW \le 10 \mu s$	I _{O+}	200	250	_	mA
Output Low Short Circuit Pulsed Current @ $V_{OUT} = 15 \text{ V}$, $V_{IN} = 0 \text{ V}$, $PW \le 10 \mu s$	I _O _	420	500	_	

DYNAMIC ELECTRICAL CHARACTERISTICS

 V_{BIAS} (V_{CC}, V_{BS}) = 15 V unless otherwise specified

Turn–On Propagation Delay @ V _S = 0 V	t _{on}	-	125	_	ns
Turn–Off Propagation Delay @ V _S = 600 V	toff	_	105	1	
Turn–On Rise Time @ C _L = 1000 pF	t _r	-	80	1	
Turn–Off Fall Time @ C _L = 1000 pF	tf	-	40	-	

TYPICAL CONNECTION



MPIC2117

LEAD DEFINITIONS

Symbol	Lead Description	
V _{CC}	Logic Supply	
IN	Logic Input for High Side Gate Driver Outputs (HO), In Phase with HO	
СОМ	Logic Ground	
V _B	High Side Floating Supply	
НО	High Side Gate Drive Output	
٧s	High Side Floating Supply Return	

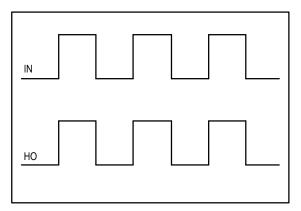


Figure 1. Input / Output Timing Diagram

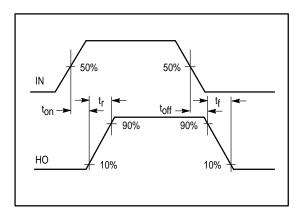
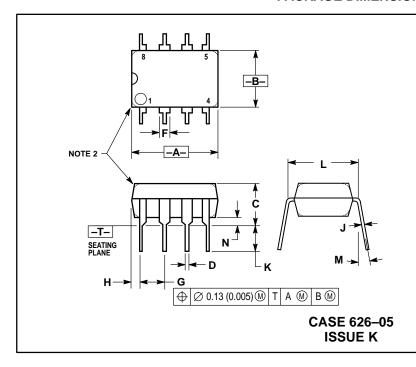


Figure 2. Switching Time Waveform Definitions

PACKAGE DIMENSIONS



- NOTES:

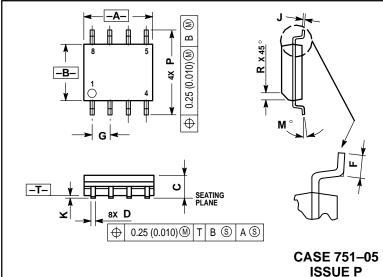
 1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.

 2. PACKAGE CONTOUR OPTIONAL (ROUND OR
- 2. PACKAGE CONTOUR OF HUMAL (ROUND OR SQUARE CORNERS).
 3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.40	10.16	0.370	0.400
В	6.10	6.60	0.240	0.260
С	3.94	4.45	0.155	0.175
D	0.38	0.51	0.015	0.020
F	1.02	1.78	0.040	0.070
G	2.54	BSC	0.100	BSC
Н	0.76	1.27	0.030	0.050
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300	BSC
M		10°		10°
N	0.76	1.01	0.030	0.040

- STYLE 1:
 PIN 1. AC IN
 2. DC + IN
 3. DC IN
 4. AC IN
 5. GROUND
 6. OUTPUT
 7. AUXILIARY
 8. VCc

 - 8. V_{CC}



- NOTES:

 1. DIMENSIONS A AND B ARE DATUMS AND T IS A DATUM SURFACE.

 2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 3. DIMENSIONS ARE IN MILLIMETER.

 4. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.

 5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

 6. DIMENSION D DOES NOT INCLUDE MOLD PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.80	5.00	
В	3.80	4.00	
С	1.35	1.75	
D	0.35	0.49	
F	0.40	1.25	
G	1.27	BSC	
J	0.18	0.25	
K	0.10	0.25	
M	0°	7°	
Р	5.80	6.20	
R	0.25	0.50	

MPIC2117

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